



**Europäisches
Patentamt**

**European
Patent Office**

**Office européen
des brevets**

Jc862 U.S. PTO
09/639288
08/15/00

Bescheinigung

Certificate

Attestation

Die angehefteten Unterla-
gen stimmen mit der
ursprünglich eingereichten
Fassung der auf dem näch-
sten Blatt bezeichneten
europäischen Patentanmel-
dung überein.

The attached documents
are exact copies of the
European patent application
described on the following
page, as originally filed.

Les documents fixés à
cette attestation sont
conformes à la version
initialement déposée de
la demande de brevet
européen spécifiée à la
page suivante.

Patentanmeldung Nr. Patent application No. Demande de brevet n°

99309842.5

Der Präsident des Europäischen Patentamts:
Im Auftrag

For the President of the European Patent Office

Le Président de l'Office européen des brevets
p.o.

I.L.C. HATTEN-HECKMAN

DEN HAAG, DEN
THE HAGUE, 12/01/00
LA HAYE, LE





Europäisches
Patentamt

European
Patent Office

Office européen
des brevets

Blatt 2 der Bescheinigung
Sheet 2 of the certificate
Page 2 de l'attestation

Anmeldung Nr.:
Application no.:
Demande n°: 99309842.5

Anmeldetag:
Date of filing:
Date de dépôt: 07/12/99

Anmelder:
Applicant(s):
Demandeur(s):
LUCENT TECHNOLOGIES INC.
Murray Hill, New Jersey 07974-0636
UNITED STATES OF AMERICA

Bezeichnung der Erfindung:
Title of the invention:
Titre de l'invention:
Improvements in or relating to integrated circuit dies

In Anspruch genommene Priorität(en) / Priority(ies) claimed / Priorité(s) revendiquée(s)

Staat: EP
State:
Pays:

Tag: 17/08/99
Date:
Date:

Aktenzeichen:
File no.
Numéro de dépôt:

EPA 99306444

Internationale Patentklassifikation:
International Patent classification:
Classification internationale des brevets:

/

Am Anmeldetag benannte Vertragsstaaten:
Contracting states designated at date of filing: AT/BE/CH/CY/DE/DK/ES/FI/FR/GB/GR/IE/IT/LI/LU/MC/NL/PT/SE
Etats contractants désignés lors du dépôt:

Bemerkungen:
Remarks:
Remarques



- 1 -

IMPROVEMENTS IN OR RELATING TO INTEGRATED CIRCUIT DIES

This invention relates to integrated circuit dies.

When an integrated circuit design nears the production stage it is usual to produce a prototype version having additional conductive pads to which connection
5 may be made for testing and de-bugging purposes. Where conventional wire bonding is used to make connections to the pads on the integrated circuit die, it is common practice to provide a plurality of conductive pads to all of which wire bond connections may be made for testing and de-bugging purposes and to a subset of which wire bond connections may be made in final production. However in the case of an integrated
10 circuit die which will be assembled as a so-called flip-chip it is necessary for the centre-to-centre pitch, or spacing, between the conductive pads to be much larger than is necessary where wire bonding is used to make the connections. This much larger pitch renders it impractical to adopt the same idea as in the wire bonding case, that is having additional pads for testing and de-bugging, because the integrated circuit die would be
15 so large that it would be uneconomic.

According to this invention an integrated circuit die includes first and second sets of conductive pads for enabling external connections to be made to the integrated circuit, there being at least a first predetermined centre-to-centre spacing between each pad of the first set and the adjacent pad or pads of the first set, and at least
20 a second predetermined centre-to-centre spacing, less than said first spacing, between each pad of the second set and the adjacent pad or pads of the first and second sets, and a passivation layer exposing only pads of the first set, or exposing pads of the first and second sets.

The pads of the first set may be larger in area than the pads of the second
25 set. The area of each pad of the first set and the first predetermined centre-to-centre spacing may be suitable for flip-chip assembly of the die, and the area of each pad of the second set and the second predetermined centre-to-centre spacing may be suitable for wire bond assembly of the die.

- 2 -

The pads of the first and second sets may be disposed in-line adjacent one or more edges of the die.

The pads of the first set may be disposed in two lines adjacent one or more edges of the die, the pads of the first set in one of the two lines being disposed in
5 staggered relationship with respect to the pads of the first set in the other of the two lines. The pads of the second set may be disposed in one of the two lines.

The first set of pads may be connected to one set of connection points in the integrated circuit, and the second set of pads may be connected to another set of connected points in the integrated circuit.

10 The invention will now be described by way of example with reference to the accompanying drawings, in which:

FIG.1 is a schematic cross section of part of an integrated circuit die embodying the invention;

FIG.2 is a schematic cross section of part of an integrated circuit die
15 embodying the invention; and

FIG.3 is a schematic plan view of part of an integrated circuit die embodying the invention.

In the various figures, which are not to scale, like references denotes like parts.

20 Referring now to Fig. 1, an integrated circuit die comprises polysilicon and metal layers shown schematically at 1 and making up the circuitry (not shown) embodied in the integrated circuit. Deposited on the surface of 1 is a first set of conductive pads 2 and a second set of conductive pads 3. The sets of conductive pads 2 and 3 are provided for the purpose of enabling connection to be made between the
25 circuitry embedded in the integrated circuit and external terminals (not shown). The first set of pads 2, which are considerably larger than the second set of pads 3, are provided for flip-chip assembly as will be described later, and are connected (by means not shown) to one set of connection points in the circuitry. The second set of pads 3 are provided to enable wire bond connections to be made to the integrated circuit e.g.
30 for testing and de-bugging purposes, and are connected (by means not shown) to another set of connection points in the circuitry. Wire bond connections may also be made to the first set of pads 2, and, as shown, all of the pads 2 and 3 have a wire bond connection 4 thereto. A passivation layer 5 of conventional passivating material is

- 3 -

provided over the surface of the integrated circuit die leaving an area uncovered on each of the pads 2 and 3 for the wire bond connections 4 thereto. The pitch, or centre-to-centre spacing, between each pad 2 of the first set and the adjacent pad or pads 2 of the first set is at least a predetermined amount required for flip-chip assembly. Currently
5 this pitch is 200 microns or 250 microns depending on the manufacturer. A smaller pitch than that required will result in manufacturing problems and a significant rejection rate. The minimum pitch for connection by wire bonding is much less and is currently 90 microns, although with present wire bonding technology the pitch could be as low as 50 microns. Thus the centre to centre spacing, or pitch, between each pad 3 of the
10 second set of pads and the adjacent pad or pads, whether it be a pad 2 of the first set of pads or a pad 3 of the second set of pads, must be at least equal to the lower spacing requirements imposed by wire bonding.

Fig.2 shows the same basic integrated circuit die shown in Fig.1 but, instead of the passivating layer 5 of Fig.1 exposing the conductive pads for wire bond
15 connections thereto, Fig.2 shows the integrated circuit die prepared for flip-chip assembly. To this end, a passivating layer 6 is provided over the surface of the die exposing only the pads 2 of the first set of pads which, as previously noted with reference to Fig.1, are of a size suitable for flip-chip assembly. It will be noted that passivating layer 6 exposes an area of pads 2 which is greater than for the wire bond
20 assembly case shown in Fig.1. Each of the pads 2 has deposited thereon a "bump" of conductive material, such as gold or solder, which by the application of heat is caused to re-flow and effect connection between its respective pad 2 and an external terminal (not shown). The mechanics of flip-chip assembly are well known and will not be described further. Because passivating material 6 covers the conductive pads 3 of the
25 second set, the necessary minimum pitch imposed by flip-chip assembly between each conductive pad 2 and the pad or pads adjacent thereto is ensured. If the pads 3 of the second set of pads were not covered by passivating material 6 the minimum pitch requirements for flip-chip assembly would not be met, and problems during such assembly would be likely with a significant rejection rate of assembled dies.

30 It will be appreciated that an integrated circuit die embodying the invention may simultaneously comply with the minimum pitch requirements for both flip-chip assembly and wire bonding without any, or any significant, increase in the size of the die. Thus the same die may be used in a flip-chip assembly process or a

- 4 -

conventional wire bonding assembly process merely by changing a single mask layer namely, the passivation layer.

The invention is not limited in its application to in-line pads. For example, two rows of pads may be provided as long as the minimum pitch requirements for flip-chip assembly and wire bonding are satisfied. Fig.3 shows in schematic plan view part of an integrated circuit die having two rows of pads. As in Figs. 1 and 2, two sets of pads are shown, the first set comprising pads 2' and 2'', and the second set comprising pads 3'. The pads 2' and 3' are arranged in a row or line adjacent to the die edge shown in Fig.3. The pads 2'' are arranged in another row or line parallel with the die edge but further therefrom. The pads 2'' may be, and as shown are, staggered in relation to the other pads 2' of the first set of pads. The pads of the first set, pads 2' and pads 2'', are larger than the pads 3' of the second set of pads and, as in Figs. 1 and 2, the larger pads may be used for flip-chip or wire bonding assembly, whereas the smaller pads 3' are intended for wire bonding assembly. As before, each of pads 2' and 2'' are pitched apart by at least the minimum required distance for flip-chip assembly, the distance being indicated schematically for two of the staggered pads by the dashed-arrowed line P. Each of the pads 3' of the second set of pads is spaced apart from the adjacent pad or pads, whether of the first or second sets of pads, by at least the minimum spacing required for wire bonding assembly. Staggering of the pads 2' and 2'' has the advantage that the periphery of the die may be reduced and, where these pads are used for wire bond assembly, it also has the advantage that their effective pitch, i.e. the pitch as measured along the die edge, matches more closely the pitch of the lead frame of an intended package.

It will be appreciated that the spacing between the pads in Figs. 1, 2 and 3 need not be uniform or symmetrical; what is required is that the spacing between each pad and the adjacent pad or pads be at least the required minimum spacing for flip-chip or wire bond assembly as the case may be.

The invention permits the same basic integrated circuit die to be used for flip-chip production, and a higher pin count version to be produced for wire bonding. Such a "dual purpose" die may be produced without an increase in die size. In effect the invention permits two separate integrated circuit dies to be produced at a minimum extra cost. Furthermore, the delay characteristics of the input/output paths and the internal parasitic characteristics of the die are substantially the same for both flip-chip

- 5 -

and wire bonding assembly options. As will be appreciated, the invention permits the decision as to whether to use flip-chip or wire bonding assembly to be made at a later stage in the production cycle.

5



Claims

1. An integrated circuit die including first and second sets of conductive pads for enabling external connections to be made to the integrated circuit, there being at least a first predetermined centre-to-centre spacing between each pad of the first set
5 and the adjacent pad or pads of the first set, and at least a second predetermined centre-to-centre spacing, less than said first spacing, between each pad of the second set and the adjacent pad or pads of the first and second sets, and a passivation layer exposing only pads of the first set, or exposing pads of the first and second sets.

2. A die as claimed in claim 1 wherein the pads of the first set are larger
10 in area than the pads of the second set.

3. A die as claimed in claim 2 wherein the area of each pad of the first set and the first predetermined centre-to-centre spacing are suitable for flip-chip assembly of the die, and the area of each pad of the second set and the second predetermined centre-to-centre spacing are suitable for wire bond assembly of the die.

15 4. A die as claimed in claim 1, 2 or 3 wherein the pads of the first and second sets are disposed in line adjacent one or more edges of the die.

5. A die as claimed in claim 1, 2 or 3 wherein the pads of the first set are disposed in two lines adjacent one or more edges of the die, the pads of the first set in one of the two lines being disposed in staggered relationship with respect to the pads
20 of the first set in the other of the two lines.

6. A die as claimed in claim 5 wherein the pads of the second set are disposed in one of the two lines.

7. A die as claimed in any preceding claim wherein the first set of pads is connected to one set of connection points in the integrated circuit, and the second set
25 of pads is connected to another set of connection points in the integrated circuit.



- 7 -

IMPROVEMENTS IN OR RELATING TO INTEGRATED CIRCUIT DIES

Abstract

An integrated circuit die (1) carries conductive pads (2) and (3) thereon, the larger pads (2) being suitable for flip-chip assembly and the smaller pads (3) being suitable for wire bond assembly. The pitch between pads (2) is at least the minimum
5 required for flip-chip assembly, whereas the pitch between each of pads (3) and the adjacent pad or pads is at least the minimum required for wire bond assembly. For wire bond assembly a passivation layer exposing all pads (2) and (3) is provided, whereas for flip-chip assembly a passivation layer 6 exposes only pads (2) so that conductive bumps (7) may be provided. The provision of pads (2) and (3) complying with the minimum
10 spacing requirements for both flip-chip and wire bond assembly enables a "dual purpose" (e.g. one set of pads being for normal production and another set for testing purposes) die to be produced without any increase in die size.

15

Fig.2



1/2

FIG. 1

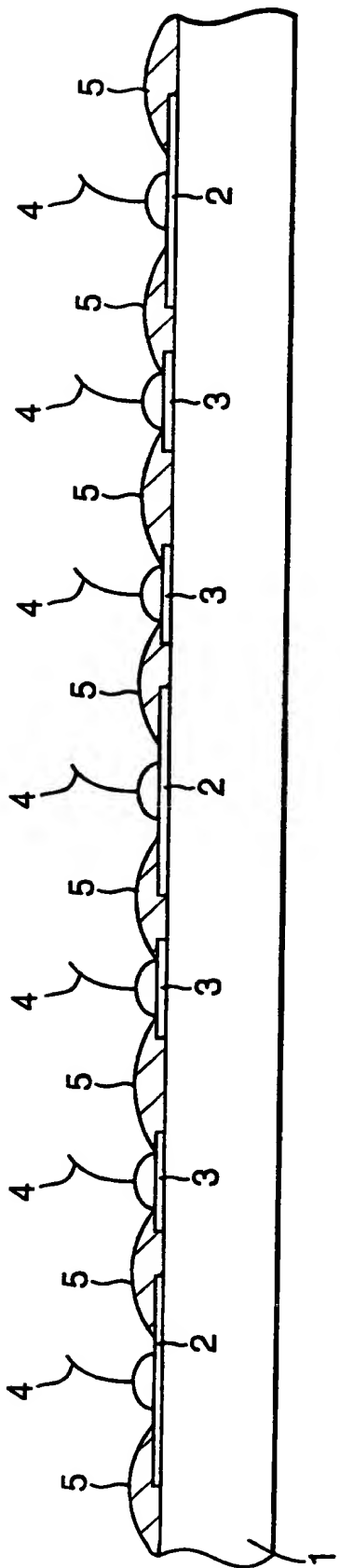
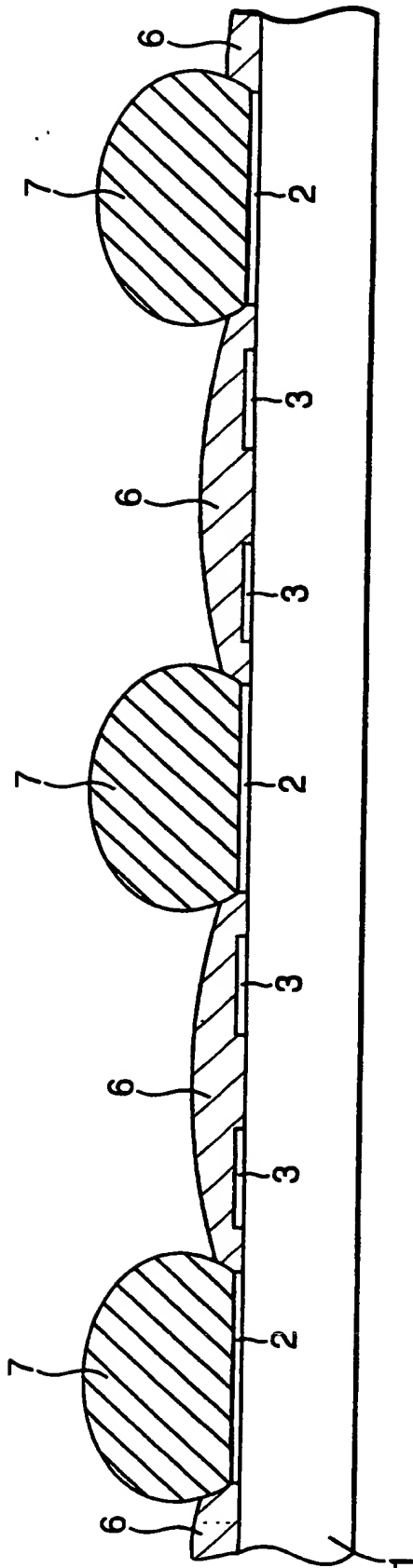


FIG. 2



2/2

FIG. 3

DIE EDGE

